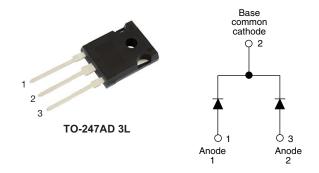


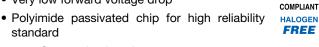
# **Hyperfast Soft Recovery Diode,** 2 x 30 A FRED Pt® Gen 4



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 30 A					
$V_{R}$	600 V					
V <sub>F</sub> at I <sub>F</sub>	1.37 V					
t <sub>rr</sub> typ.	see Recovery table					
$T_J$ max.	175 °C					
Package	TO-247AD 3L					
Circuit configuration	Common cathode					

#### **FEATURES**

- Gen 4 FRED Pt® technology
- Low I<sub>RRM</sub> and reverse recovery charge
- · Very low forward voltage drop
- standard



- 175 °C operating junction temperature
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

#### **DESCRIPTION**

Gen 4 Fred technology, state of the art, ultralow V<sub>F</sub>, soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Cathode to anode voltage	V <sub>R</sub>		600	V			
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 122 °C	30	^			
Non-repetitive peak surge current, per leg	I <sub>FSM</sub>	$T_C = 25$ °C, $t_p = 8.3$ ms, half sine wave	240	A			
Operating junction and storage temperatures	$T_J, T_{Stg}$		-55 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	600	-	-			
En est eller		I <sub>F</sub> = 30 A	-	1.65	2	V		
		I <sub>F</sub> = 60 A	-	1.95	-			
	V	I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C	-	1.44	-			
Forward voltage	$V_{F}$	I <sub>F</sub> = 60 A, T <sub>J</sub> = 125 °C	-	1.78	-			
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.37	1.6			
		I <sub>F</sub> = 60 A, T <sub>J</sub> = 150 °C	-	1.68	-			
Poverse leekege ourrent		V <sub>R</sub> = V <sub>R</sub> rated	-	-	50			
Reverse leakage current	I <sub>R</sub>	$T_J = 125  ^{\circ}\text{C},  V_R = V_R  \text{rated}$	-	-	500	μA		
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	18.3	-	pF		



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST C	MIN.	TYP.	MAX.	UNITS		
Reverse recovery time	+	T <sub>J</sub> = 25 °C	$I_F = 30 \text{ A}$ $dI_F/dt = 1000 \text{ A/}\mu\text{s}$ $V_R = 400 \text{ V}$	1	55	-	- ns	
	t <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	75	-		
Dook roopyon, gurrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	13	-	A	
Peak recovery current		T <sub>J</sub> = 125 °C		-	23	-		
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	500	-	nC	
		T <sub>J</sub> = 125 °C		-	1250	-		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction to case	$R_{thJC}$		-	-	1			
Thermal resistance, junction to ambient	$R_{thJA}$	Typical socket mount	-	-	40	°C/W		
Thermal resistance, case to heat sink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.4	-			
Woight			-	6.0	-	g		
Weight			-	0.21	-	OZ.		
Mounting torque			6.0 (5)	-	12 (20)	kgf · cm (lbf · in)		
Marking device		Case style TO-247AD 3L	C4PH6006L					

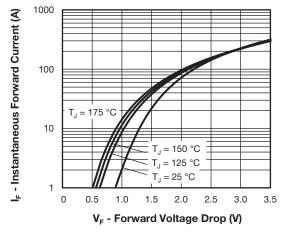


Fig. 1 - Typical Forward Voltage Drop Characteristics

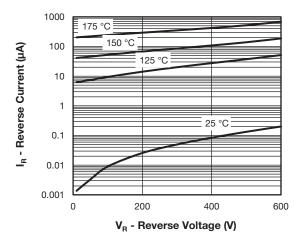


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

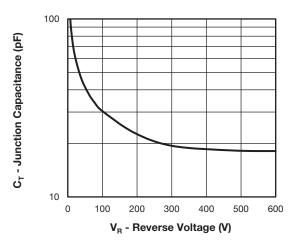


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

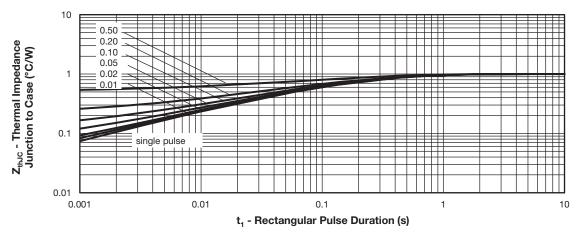


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

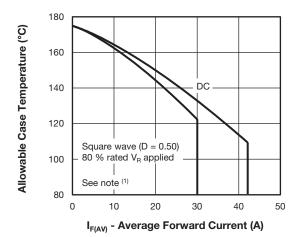


Fig. 5 - Max. Allowable Case Temperature vs.

Average Forward Current

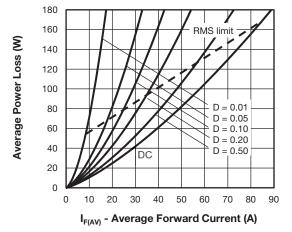


Fig. 6 - Forward Power Loss Characteristics

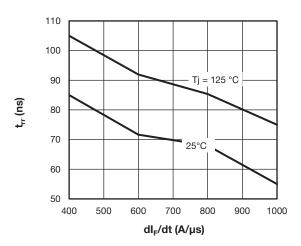
#### Note

<sup>(1)</sup> Formula used: T<sub>C</sub> = T<sub>J</sub> - (P<sub>d</sub> + P<sub>dREV</sub>) x R<sub>thJC</sub>; Pd = forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see Fig.5) P<sub>dREV</sub> = inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R</sub> = rated V<sub>R</sub>



#### www.vishay.com

# Vishay Semiconductors



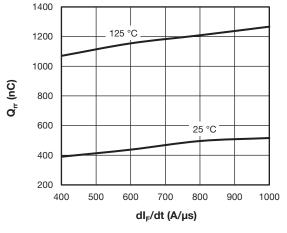


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

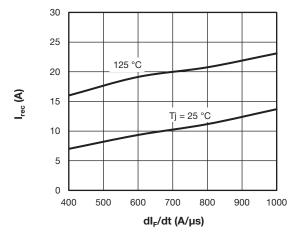
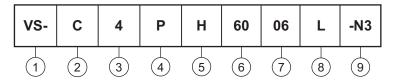


Fig. 9 - Typical Reverse Recovery vs. dl<sub>F</sub>/dt



### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

2 - Circuit configuration:

C = common cathode

3 - FRED Gen 4

P = TO-247 package

5 - Process type:

H = hyperfast recovery

6 - Current rating (60 = 60 A)

7 - Voltage rating (06 = 600 V)

8 - L = long lead

9 - Environmental digit:

-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-C4PH6006L-N3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95626				
Part marking information	www.vishay.com/doc?95007				



### **TO-247AD 3L**

### **DIMENSIONS** in millimeters and inches



View B

	MILLIMETERS INCHES					
SYMBOL	IVIILLIIV	IETEKS	INC	NOTES		
01111202	MIN.	MAX.	MIN.	MAX.		
Α	4.65	5.31	0.183	0.209		
A1	2.21	2.59	0.087	0.102		
A2	1.50	2.49	0.059	0.098		
b	0.99	1.40	0.039	0.055		
b1	0.99	1.35	0.039	0.053		
b2	1.65	2.39	0.065	0.094		
b3	1.65	2.34	0.065	0.092		
b4	2.59	3.43	0.102	0.135		
b5	2.59	3.38	0.102	0.133		
С	0.38	0.89	0.015	0.035		
c1	0.38	0.84	0.015	0.033		
D	19.71	20.70	0.776	0.815	3	
D1	13.08	-	0.515	-	4	

Section C - C, D - D, E - E

SYMBOL	MILLIMETERS		INC	INCHES		
OTWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D2	0.51	1.30	0.020	0.051		
E	15.29	15.87	0.602	0.625	3	
E1	13.46	-	0.53	-		
е	5.46	BSC	0.215	BSC		
ØК	0.2	0.254		0.010		
L	19.81	20.32	0.780	0.800		
L1	3.71	4.29	0.146	0.169		
ØΡ	3.56	3.66	0.14	0.144		
Ø P1	-	6.98	-	0.275		
Q	5.31	5.69	0.209	0.224		
R	4.52	5.49	0.178	0.216		
S	5.51 BSC		0.217 BSC			

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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